NSN 5961-01-105-8233 Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Plastic
Overall Length:
Between 0.390 inches and 0.420 inches
Overall Height:
Between 0.160 inches and 0.190 inches
Overall Width:
Between 0.325 inches and 0.355 inches
Mounting Facility Quantity:
1
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 repetitive peak reverse voltage, peak total value and 75.0 nonrepetitive peak reverse voltage, peak total value
Current Rating Per Characteristic:
8.00 amperes forward current, total rms universal
Power Rating Per Characteristic:
0.5 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius ambient air
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
<del>-</del>
Demilitarization:
No
Fiig:
A110a0